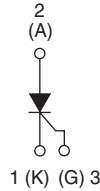


Phase Control SCR, 10 A



TO-220AB



DESCRIPTION/FEATURES

The 10TTS08 High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

Typical applications are in input rectification and crow-bar (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

Also available in SMD-220 package (series 10TTS08S).

This product has been designed and qualified for industrial level.

PRODUCT SUMMARY

| | |
|----------------|----------|
| V_T at 6.5 A | < 1.15 V |
| I_{TSM} | 140 A |
| V_{RRM} | 800 V |

OUTPUT CURRENT IN TYPICAL APPLICATIONS

| APPLICATIONS | SINGLE-PHASE BRIDGE | THREE-PHASE BRIDGE | UNITS |
|---|---------------------|--------------------|-------|
| Capacitive input filter $T_A = 55\text{ °C}$, $T_J = 125\text{ °C}$, common heatsink of 1 °C/W | 13.5 | 17 | A |

MAJOR RATINGS AND CHARACTERISTICS

| PARAMETER | TEST CONDITIONS | VALUES | UNITS |
|-------------------|-----------------------------|-------------|------------|
| $I_{T(AV)}$ | Sinusoidal waveform | 6.5 | A |
| $I_{T(RMS)}$ | | 10 | |
| V_{RRM}/V_{DRM} | | 800 | V |
| I_{TSM} | | 140 | A |
| V_T | 6.5 A, $T_J = 25\text{ °C}$ | 1.15 | V |
| dV/dt | | 150 | V/ μ s |
| dI/dt | | 100 | A/ μ s |
| T_J | Range | - 40 to 125 | °C |

VOLTAGE RATINGS

| PART NUMBER | V_{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V | V_{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V | I_{RRM}/I_{DRM} AT 125 °C mA |
|-------------|---|--|-----------------------------------|
| 10TTS08 | 800 | 800 | 1.0 |

10TTS08 High Voltage Series



Vishay High Power Products Phase Control SCR, 10 A

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|---|-----------------|--|-----------------------------------|---------------|----|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum average on-state current | $I_{T(AV)}$ | $T_C = 112\text{ }^\circ\text{C}$, 180° conduction half sine wave | 6.5 | A | |
| Maximum RMS on-state current | $I_{T(RMS)}$ | | 10 | | |
| Maximum peak, one-cycle, non-repetitive surge current | I_{TSM} | 10 ms sine pulse, rated V_{RRM} applied, $T_J = 125\text{ }^\circ\text{C}$ | 120 | | |
| | | 10 ms sine pulse, no voltage reapplied, $T_J = 125\text{ }^\circ\text{C}$ | 140 | | |
| Maximum I^2t for fusing | I^2t | 10 ms sine pulse, rated V_{RRM} applied, $T_J = 125\text{ }^\circ\text{C}$ | 72 | A^2s | |
| | | 10 ms sine pulse, no voltage reapplied, $T_J = 125\text{ }^\circ\text{C}$ | 100 | | |
| Maximum $I^2\sqrt{t}$ for fusing | $I^2\sqrt{t}$ | $t = 0.1$ to 10 ms, no voltage reapplied, $T_J = 125\text{ }^\circ\text{C}$ | 1000 | $A^2\sqrt{s}$ | |
| Maximum on-state voltage drop | V_{TM} | 6.5 A, $T_J = 25\text{ }^\circ\text{C}$ | 1.15 | V | |
| On-state slope resistance | r_t | $T_J = 125\text{ }^\circ\text{C}$ | 17.3 | $m\Omega$ | |
| Threshold voltage | $V_{T(TO)}$ | | 0.85 | V | |
| Maximum reverse and direct leakage current | I_{RM}/I_{DM} | $V_R = \text{Rated } V_{RRM}/V_{DRM}$ | $T_J = 25\text{ }^\circ\text{C}$ | 0.05 | mA |
| | | | $T_J = 125\text{ }^\circ\text{C}$ | 1.0 | |
| Typical holding current | I_H | Anode supply = 6 V, resistive load, initial $I_T = 1$ A | 30 | | |
| Maximum latching current | I_L | Anode supply = 6 V, resistive load | 50 | | |
| Maximum rate of rise of off-state voltage | dV/dt | $T_J = 25\text{ }^\circ\text{C}$ | 150 | $V/\mu s$ | |
| Maximum rate of rise of turned-on current | dI/dt | | 100 | $A/\mu s$ | |

| TRIGGERING | | | | |
|---|-------------|---|--------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum peak gate power | P_{GM} | | 8.0 | W |
| Maximum average gate power | $P_{G(AV)}$ | | 2.0 | |
| Maximum peak positive gate current | $+I_{GM}$ | | 1.5 | A |
| Maximum peak negative gate voltage | $-V_{GM}$ | | 10 | V |
| Maximum required DC gate current to trigger | I_{GT} | Anode supply = 6 V, resistive load, $T_J = -65\text{ }^\circ\text{C}$ | 20 | mA |
| | | Anode supply = 6 V, resistive load, $T_J = 25\text{ }^\circ\text{C}$ | 15 | |
| | | Anode supply = 6 V, resistive load, $T_J = 125\text{ }^\circ\text{C}$ | 10 | |
| Maximum required DC gate voltage to trigger | V_{GT} | Anode supply = 6 V, resistive load, $T_J = -65\text{ }^\circ\text{C}$ | 1.2 | V |
| | | Anode supply = 6 V, resistive load, $T_J = 25\text{ }^\circ\text{C}$ | 1 | |
| | | Anode supply = 6 V, resistive load, $T_J = 125\text{ }^\circ\text{C}$ | 0.7 | |
| Maximum DC gate voltage not to trigger | V_{GD} | $T_J = 125\text{ }^\circ\text{C}$, $V_{DRM} = \text{Rated value}$ | 0.2 | mA |
| Maximum DC gate current not to trigger | I_{GD} | | 0.1 | |

| SWITCHING | | | | |
|-------------------------------|----------|-----------------------------------|--------|---------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Typical turn-on time | t_{gt} | $T_J = 25\text{ }^\circ\text{C}$ | 0.8 | μs |
| Typical reverse recovery time | t_{rr} | $T_J = 125\text{ }^\circ\text{C}$ | 3 | |
| Typical turn-off time | t_q | | 100 | |



10TTS08 High Voltage Series

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| THERMAL AND MECHANICAL SPECIFICATIONS | | | | |
|---|----------------|--------------------------------------|-------------|------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Maximum junction and storage temperature range | T_J, T_{Stg} | | - 40 to 125 | °C |
| Maximum thermal resistance, junction to case | R_{thJC} | DC operation | 1.5 | °C/W |
| Maximum thermal resistance, junction to ambient | R_{thJA} | | 62 | |
| Typical thermal resistance, case to heatsink | R_{thCS} | Mounting surface, smooth and greased | 0.5 | |
| Approximate weight | | | 2 | g |
| | | | 0.07 | oz. |
| Mounting torque | minimum | | 6 (5) | kgf · cm |
| | maximum | | 12 (10) | (lbf · in) |
| Marking device | | Case style TO-220AC | 10TTS08 | |

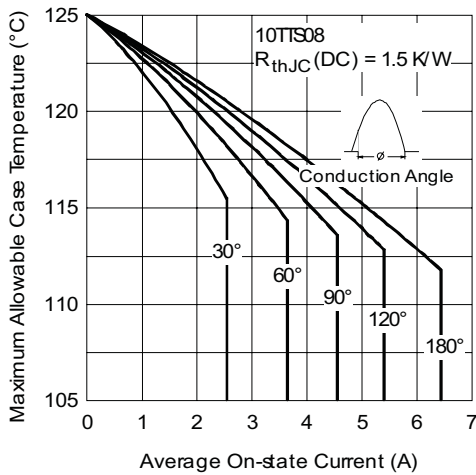


Fig. 1 - Current Rating Characteristics

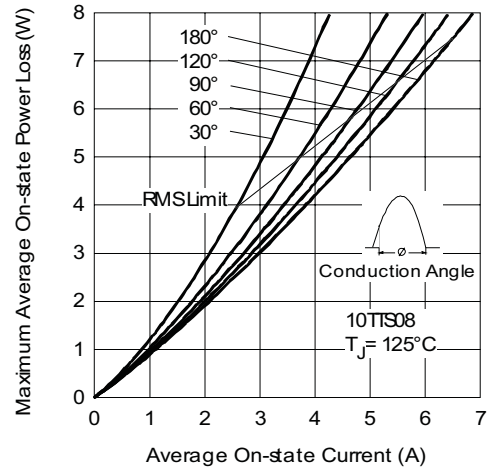


Fig. 3 - On-State Power Loss Characteristics

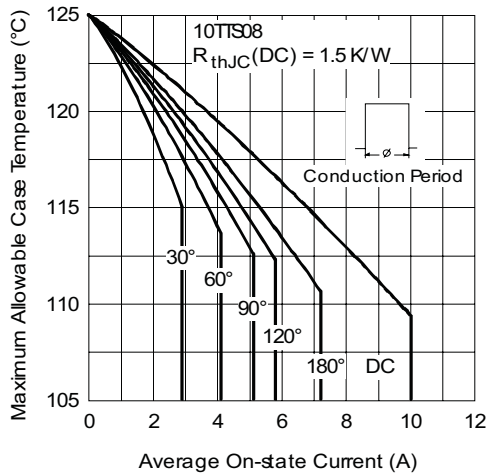


Fig. 2 - Current Rating Characteristic

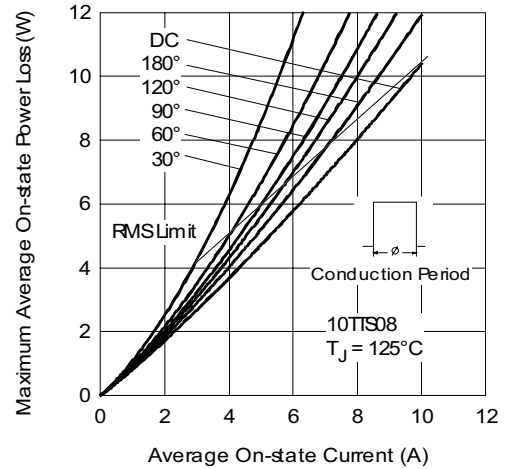


Fig. 4 - On-State Power Loss Characteristics

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Vishay High Power Products Phase Control SCR, 10 A

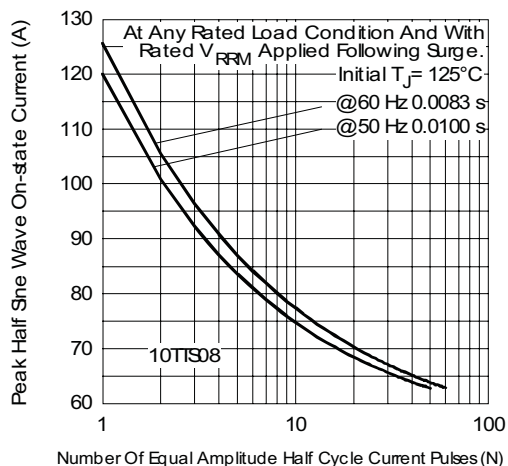


Fig. 5 - Maximum Non-Repetitive Surge Current

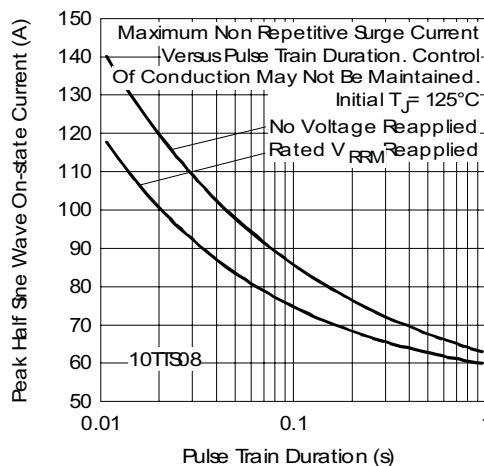


Fig. 6 - Maximum Non-Repetitive Surge Current

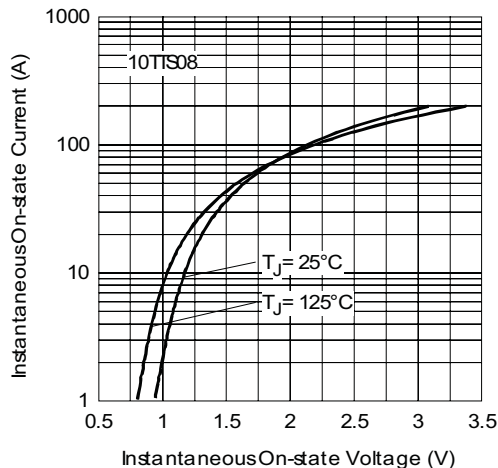


Fig. 7 - On-State Voltage Drop Characteristics

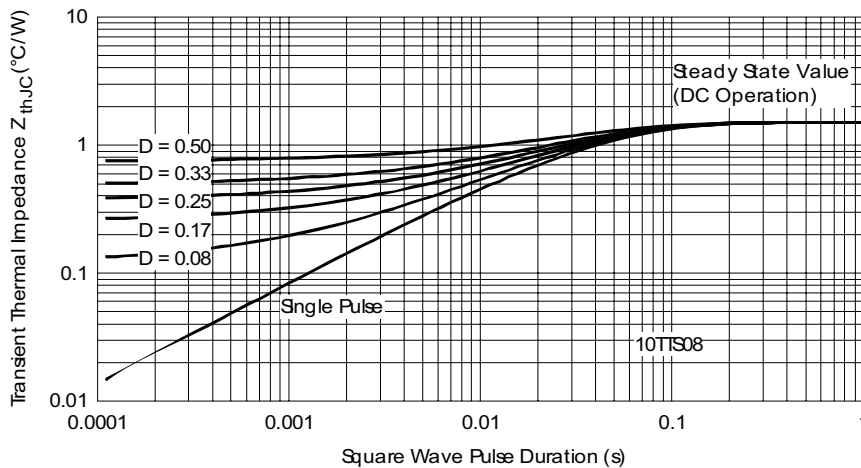


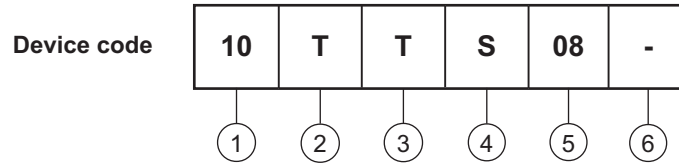
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



10TTS08 High Voltage Series

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ORDERING INFORMATION TABLE



- 1** - Current rating
- 2** - Circuit configuration:
T = Single thyristor
- 3** - Package:
T = TO-220AC
- 4** - Type of silicon:
S = Converter grade
- 5** - Voltage code x 100 = V_{RRM}
- 6** -
 - None = Standard production
 - PbF = Lead (Pb)-free

| LINKS TO RELATED DOCUMENTS | |
|----------------------------|---|
| Dimensions | http://www.vishay.com/doc?95222 |
| Part marking information | http://www.vishay.com/doc?95225 |



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